

^{57}Ti β^- decay (98 ms) 2005Li53

Type	Author	Citation	History Literature Cutoff Date
Full Evaluation	Balraj Singh	ENSDF	12-Apr-2010

Parent: ^{57}Ti : E=0.0; $J^\pi=(5/2^-)$; $T_{1/2}=98$ ms 5; $Q(\beta^-)=10.64\times10^3$ 51; % β^- decay=100.0

$^{57}\text{Ti-T}_{1/2}$: Deduced from fit of the fragment- β -decay curve considering the exponential decay of the parent, exponential growth, and decay of the daughter ^{57}V , and a linear background term. The value obtained was compared with that obtained from fragment- β - γ decay curves for each of the transitions assigned to ^{57}Ti (2005Li43). See Adopted Levels of ^{57}Ti for previous half-life measurements.

$^{57}\text{Ti-J}^\pi$: From ^{57}Ti Adopted Levels.

$^{57}\text{Ti-Q}(\beta^-)$: from 2009AuZZ, 2003Au03.

2005Li53: ^{57}Ti isotope produced in fragmentation of $^{86}\text{Kr}^{34+}$ beam on a ^9Be target. Secondary fragments were selected using the A1900 fragment separator. Fragment identification was performed by a combination of multiple energy-loss signals and time of flight method. Measured $E\gamma$, $I\gamma$, $\gamma\gamma$, $\gamma\beta(t)$, lifetime with 12 Ge detectors from the MSU segmented Ge array and double-sided Si microstrip detector.

 ^{57}V Levels

$E(\text{level})^\dagger$	J^π
0.0	(7/2 ⁻)
113.2 4	
174.8 4	
1731.9 4	
1754.3? 5	
2036.3 4	
2475.6 5	

[†] from least-squares fit to $E\gamma$'s.

 β^- radiations

$E(\text{decay})$	$E(\text{level})$	$I\beta^-$ [#]	$\text{Log } f\beta^-$	Comments
$(8.2\times10^3$ 5)	2475.6	7.3 7	5.0	av $E\beta=3.81\times10^3$ 25
$(8.6\times10^3$ 5)	2036.3	16.6 21	4.8	av $E\beta=4.03\times10^3$ 25
$(8.9\times10^3$ @ 5)	1754.3?	16 2	4.9	av $E\beta=4.17\times10^3$ 25
$(8.9\times10^3$ 5)	1731.9	1.1 7	6.0	av $E\beta=4.18\times10^3$ 25
$(1.05\times10^4$ 5)	174.8	5 5	5.7	av $E\beta=4.94\times10^3$ 25
$(1.06\times10^4$ 5)	0.0	53.8 23	4.7	av $E\beta=5.02\times10^3$ 25

[†] deduced by the evaluator from γ -ray intensity balances and the ground state feeding deduced by 2005Li53 from the total number of ^{57}Ti nuclei implanted in the Double-sided Si microstrip detector (DSSD). The listed β feedings should be treated as apparent values.

[‡] All values are considered as lower limits.

[#] Absolute intensity per 100 decays.

[@] Existence of this branch is questionable.

 $^{57}\text{Ti} \beta^-$ decay (98 ms) 2005Li53 (continued) $\gamma(^{57}\text{V})$

I γ normalization: Absolute γ -ray intensities are given in [2005Li43](#).

E $_{\gamma}$	I $_{\gamma}^{\dagger}$	E $_i$ (level)	E $_f$	J $^{\pi}_f$	Comments
(61.7)	11 3	174.8	113.2		
113.1 4	14 1	113.2	0.0	(7/2 $^-$)	
174.8 4	31 2	174.8	0.0	(7/2 $^-$)	
744.0 4	2.3 4	2475.6	1731.9		
1557.3 5	2.2 5	1731.9	174.8		
1579.4 [‡] 4	16 2	1754.3?	174.8		
1732.2 6	1.2 2	1731.9	0.0	(7/2 $^-$)	
1861.5 4	14 2	2036.3	174.8		
1922.9 5	2.6 5	2036.3	113.2		
^x 2003.7 6	1.8 5				
^x 2114.6 5	0.7 3				
2300.4 4	5.0 5	2475.6	174.8		

† Absolute intensity per 100 decays.

‡ Placement of transition in the level scheme is uncertain.

x γ ray not placed in level scheme.

